

## ペロブスカイト太陽電池における電子輸送層界面の制御

### <mark>村上拓郎\*1, 宮寺哲彦1, 舩木 敬1, Cojocaru</mark> Ludmila², Kazaoui Said¹, 近松真之¹, 瀬川浩司<sup>2, 3</sup>

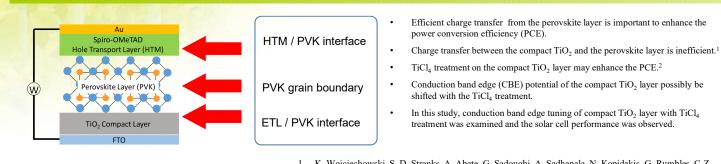
<sup>1</sup> 産業技術総合研究所・太陽光発電研究センター, 305-8565 茨城県つくば市東1-1-1

<sup>2</sup> 東京大学・先端科学技術研究センター, 153-8904 東京都目黒区駒場4-6-1

<sup>3</sup> 東京大学・大学院総合文化研究科, 153-8902 東京都目黒区駒場3-8-1

Email: takurou-murakami@aist.go.jp

#### Introduction



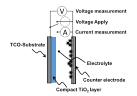
Scheme 1. Structure of the PSC in this study

- K. Wojciechowski, S. D. Stranks, A. Abate, G. Sadoughi, A. Sadhanala, N. Kopidakis, G. Rumbles, C-Z. Li, R. H. Friend, A. K.-Y. Jen, H. J. Snaith, ACS Nano, 8, 12701-12709 (2014).
- 2. L. Cojocaru, S. Uchida, Y. Sanehira, J. Nakazaki, T. Kubo, H. Segawa, Chem. Lett. 44, 674-676 (2015).

#### Experiment

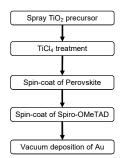
Electrochemical measurement for conduction band edge evaluation:

The sandwich cell with compact TiO<sub>2</sub> substrate and platinized counter electrodes was fabricated and iodide / tir-iodide electrolyte was injected between two electrodes.
Relation between open circuit voltage (Voc) and electron density was measured with charge extraction methods.

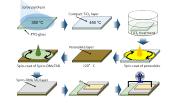


Fermi Level

Scheme 2. The electrochemical cell for the charge extraction measurement.



Scheme 3. Evaluation of the conduction band edge with the charge extraction method.



Scheme 5. Fabrication process of the cells.

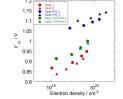
Scheme 4. The flow chart of the cell fabrication.

#### Acknowledgement

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# Results and discussion



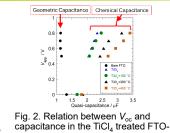


Fig. 1. Relation between  $V_{\rm oc}$  and electron density in the compact  ${\rm TiO_2}$  electrodes

after heating.

 $V_{\rm oc}$  increased with the TiCl<sub>4</sub> treatment at the same electron density and then it decreased

alass electrodes

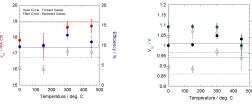


Fig. 3. Relation between heat temperature and *I-V* parameter. Solid line: Reverse sweep, Dashed line: Forward sweep

 $J_{sc}$  increased and  $V_{oc}$  decreased with the heating temperature after TiCl<sub>4</sub> treatment.

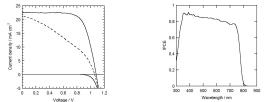


Fig. 4. *I-V* curve and IPCE spectrum of the best efficiency cell

The TiCl<sub>4</sub> treated cell subjected to subsequent heating at 300 °C exhibited the best performance, with the power conversion efficiency of the cell being 17% under optimized conditions.

#### Conclusion

- CBE of the compact TiO<sub>2</sub> layer may change with the TiCl<sub>4</sub> treatment and the post-heating.
- The best CBE level for electron transfer in the PSC can be tuned with heating at 300°C after TiCl<sub>4</sub> treatment.